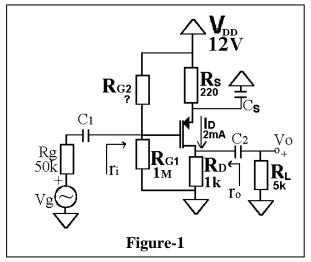
## EE232-INTRODUCTION TO ELECTRONICS-FALL 2009 EXERCISE-M4

Q-1- $\beta$ =6mA/V<sup>2</sup> and V<sub>t</sub>=-1V are given for the MOSFET in Figure-1.

- a) Find  $R_{\rm G2}$  in order to get  $I_D \! = \! 2mA$  in DC case.
- b)Find the power dissipiated on the MOSFET.
- c) Find the ac input (ri) and output (ro) resistances.
- d) Find the ac gain (Vo/Vi) of the circuit.
- e) Find the total ac gain (Vo/Vg) of the circuit.



#### **SOLUTION**

a)

### **Source voltage:**

$$Vs = V_{DD} - I_D R_S$$
$$Vs = 12 - 2mAx0.22\Omega$$
$$Vs = 11.56V$$

## **Gate Voltage:**

The transistor is assumed in the saturation region

$$I_D = \frac{\beta}{2} (V_{GS} - V_t)^2$$

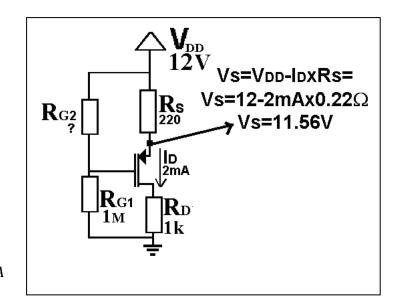
$$I_D = \frac{6mA/V^2}{2} (V_G - V_S - V_t)^2$$

$$I_D = \frac{6mA/V^2}{2} (V_G - 11.56V - (-1))^2 = 2mA$$

$$(V_G - 11.56V - (-1))^2 = \frac{2}{3}$$

$$(V_G - 11.56V - (-1)) = -0.82$$

$$V_G = 9.74V$$



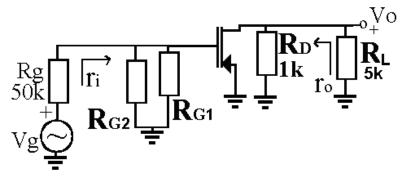
#### R<sub>G2</sub>:

$$V_G = \frac{R_{G1}}{R_{G2} + R_{G1}} V_{DD} = 9.74V \Rightarrow \frac{R_{G1}}{R_{G2} + R_{G1}} = \frac{9.74V}{12V} \Rightarrow R_{G2} \cong 232k\Omega$$

b)

#### **Dissipated Power on MOSFET:**

$$P_{MOS} = I_D x V_{SD} = 2mAx(V_S - V_D) = 2mAx(11.56V - I_D x R_D) = 2mAx9.56V = 19.12mW$$



ac case of the circuit.

c)

## input resistance

$$ri = R_{G1} // R_{G2} = 188k\Omega$$

Note that the input resistance of the MOSFET is infinite.

### **Output resistance**

$$ro=R_D=1k$$

Note that  $V_A$  is infinite, therefore the ac resistance seen from the drain is infinite.

d)

# the gain Vo/Vi

$$\frac{V_o}{V_i} = -\frac{g_m R_d}{1 + g_m R_s} = \frac{-g_m x R_D // R_L}{1 + 0} = -\sqrt{2\beta I_D} x 0.83k\Omega \cong -4.1$$

e)

# the gain Vo/Vg

$$\frac{V_o}{V_g} = \frac{V_i}{V_g} \frac{V_o}{V_i} = \frac{R_{G2} /\!/ R_{G1}}{R_g + R_{G2} /\!/ R_{G1}} x(-4.1) \cong -3.2$$